



**浩畅半导体**  
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LL4148 LL-34

SILICON EPITAXIAL PLANAR DIODE

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客户确认：

公司签章：

部门

工程部

品保部

采购部

签名

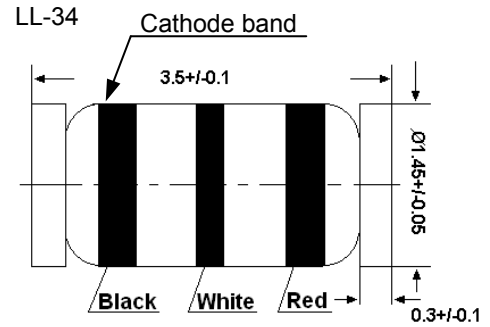
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SILICON EPITAXIAL PLANAR DIODE

fast switching diode in MiniMELF case especially suited for automatic surface mounting.  
Identical electrically to standard JEDEC 1N4148



Glass case MiniMELF  
Dimensions in mm

**Absolute Maximum Ratings ( $T_a = 25\text{ }^\circ\text{C}$ )**

Parameter	Symbol	Value	Unit
Reverse Voltage	$V_R$	75	V
Peak Reverse Voltage	$V_{RM}$	100	V
Rectified Current (Average) Half Wave Rectification with Resist. Load at $T_{amb} = 25\text{ }^\circ\text{C}$ and $f \geq 50\text{ Hz}$	$I_O$	150 <sup>1)</sup>	mA
Repetitive Peak Forward Current	$I_{FRM}$	500	mA
Peak Forward Surge Current at $t_p = 1\mu\text{s}$	$I_{FSM}$	2	A
Power Dissipation	$P_{tot}$	500 <sup>1)</sup>	mW
Junction Temperature	$T_j$	175	$^\circ\text{C}$
Storage Temperature Range	$T_S$	-65 to +175	$^\circ\text{C}$

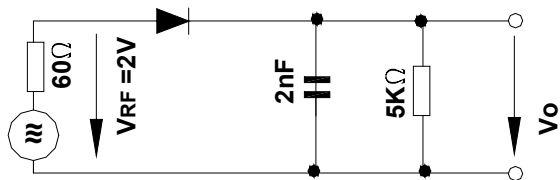
<sup>1)</sup> Valid provided that electrodes are kept at ambient temperature.

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## Characteristics at $T_j = 25\text{ }^\circ\text{C}$

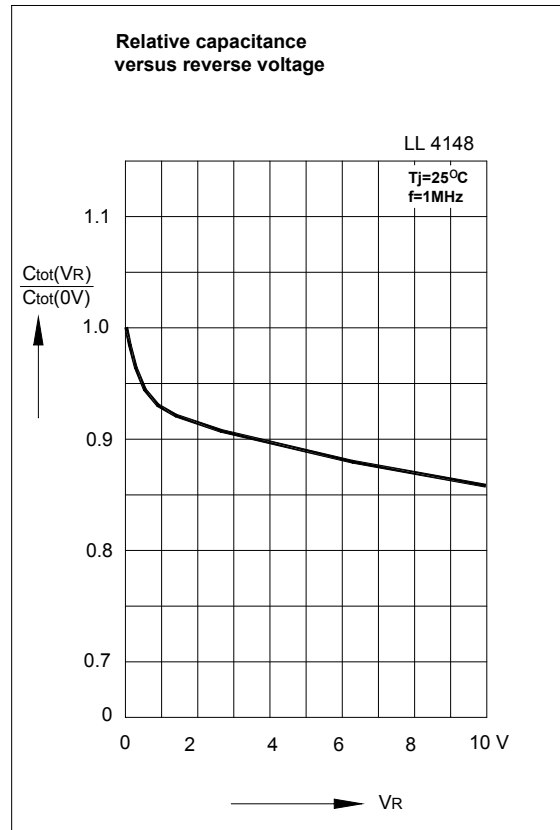
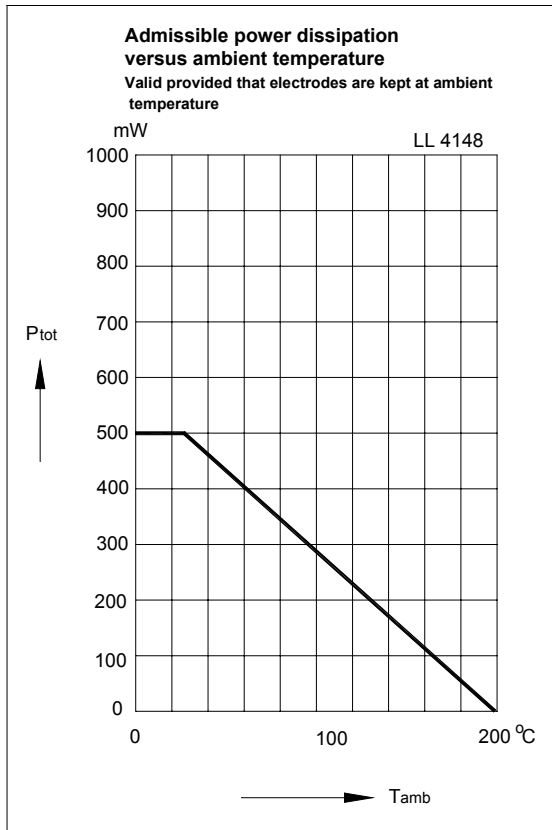
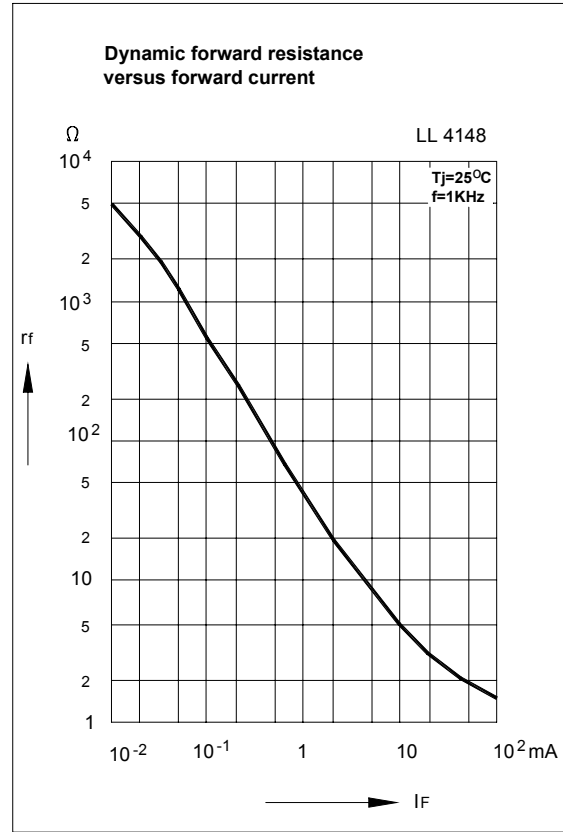
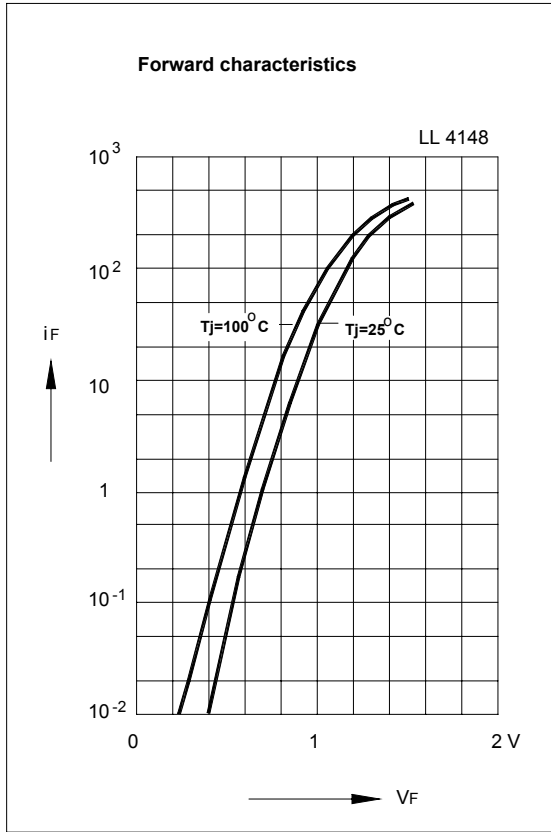
Parameter	Symbol	Min.	Max.	Unit
Forward Voltage at $I_F = 10\text{ mA}$	$V_F$	-	1	V
Leakage Current at $V_R = 20\text{ V}$ at $V_R = 75\text{ V}$ at $V_R = 20\text{ V}, T_j = 150\text{ }^\circ\text{C}$	$I_R$ $I_R$ $I_R$	- - -	25 5 50	nA $\mu\text{A}$ $\mu\text{A}$
Reverse Breakdown Voltage tested with $100\text{ }\mu\text{A}$ Pulses	$V_{(BR)R}$	100	-	V
Capacitance at $V_F = V_R = 0$	$C_{tot}$	-	4	pF
Voltage Rise when Switching ON tested with $50\text{ mA}$ Forward Pulses $t_p = 0.1\text{ s}$ , Rise Time $< 30\text{ ns}$ , $f_p = 5\text{ to }100\text{ KHz}$	$V_{fr}$	-	2.5	V
Reverse Recovery Time from $I_F = 10\text{ mA}$ to $I_R = 1\text{ mA}$ , $V_R = 6\text{ V}$ , $R_L = 100\text{ }\Omega$	$t_{rr}$	-	4	ns
Thermal Resistance Junction to Ambient Air	$R_{thA}$	-	$0.35^{(1)}$	K/mW
Rectification Efficiency at $f = 100\text{ MHz}$ , $V_{RF} = 2\text{ V}$	$\eta_v$	0.45	-	-

<sup>1)</sup> Valid provided that electrodes are kept at ambient temperature.



**Rectification Efficiency Measurement Circuit**

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